

#18 / Response
10/20/02
AS

1201.63407

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re U.S. Patent Application

Applicant: Nayfeh et al.

Serial No. 09/496,506

Filed: February 2, 2000

For: SILICON NANOPARTICLE
FIELD EFFECT TRANSISTOR
AND TRANSISTOR MEMORY
DEVICE

Art Unit: 2811

Examiner: Crane, S.

) I hereby certify that this paper is being facsimile
) transmitted to the U.S. Patent and Trademark Office on
) this date.

) Oct. 4, 2002

) Date
) please print

) Appr. April 11, 2000

) Ali B. N.) Registration No. 42874

) Attorney for Applicant

RESPONSE CAssistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Office Action mailed June 4, 2002, which has been made final, and in further response to the Advisory Action mailed September 18, 2002, please consider the following remarks.

REMARKS

Claims 1, 5, and 8 stand rejected under 35 U.S.C. § 102(b) as being anticipated by Chen. Claim 4 stands rejected under 35 U.S.C. § 103(a) as being unpatentable over Chen. Claims 6 and 7 stand rejected under 35 U.S.C. § 103(a) as being unpatentable over Chen in